Pulse Width Modulator Control Circuit

SG3525A

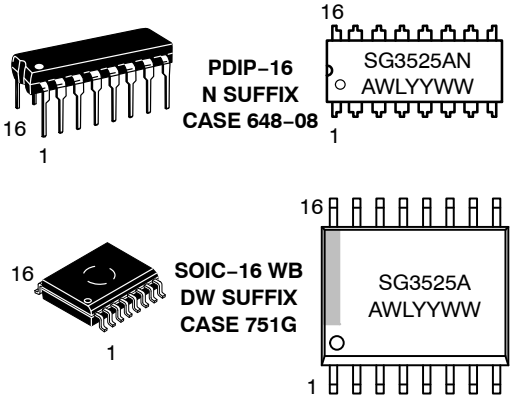
The SG3525A pulse width modulator control circuit offers improved performance and lower external parts count when implemented for controlling all types of switching power supplies. The on−chip +5.1 V reference is trimmed to ±1% and the error amplifier has an input common−mode voltage range that includes the reference voltage, thus eliminating the need for external divider resistors. A sync input to the oscillator enables multiple units to be slaved or a single unit to be synchronized to an external system clock. A wide range of deadtime can be programmed by a single resistor connected between the C_T and Discharge pins. This device also features built−in soft−start circuitry, requiring only an external timing capacitor. A shutdown pin controls both the soft−start circuitry and the output stages, providing instantaneous turn off through the PWM latch with pulsed shutdown, as well as soft−start recycle with longer shutdown commands. The under voltage lockout inhibits the outputs and the changing of the soft−start capacitor when V_{CC} is below nominal. The output stages are totem−pole design capable of sinking and sourcing in excess of 200 mA. The output stage of the SG3525A features NOR logic resulting in a low output for an off−state.

Features

- 8.0 V to 35 V Operation
- 5.1 V ±1.0% Trimmed Reference
- 100 Hz to 400 kHz Oscillator Range
- Separate Oscillator Sync Pin
- Adjustable Deadtime Control
- Input Undervoltage Lockout
- Latching PWM to Prevent Multiple Pulses
- Pulse−by−Pulse Shutdown
- Dual Source/Sink Outputs: ±400 mA Peak
- Pb−Free Packages are Available*

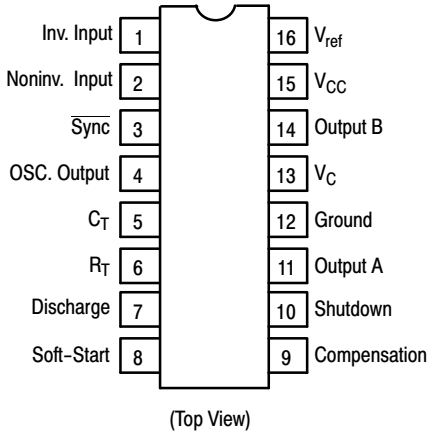
*For additional information on our Pb−Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MARKING DIAGRAMS



A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week

PIN CONNECTIONS



(Top View)

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

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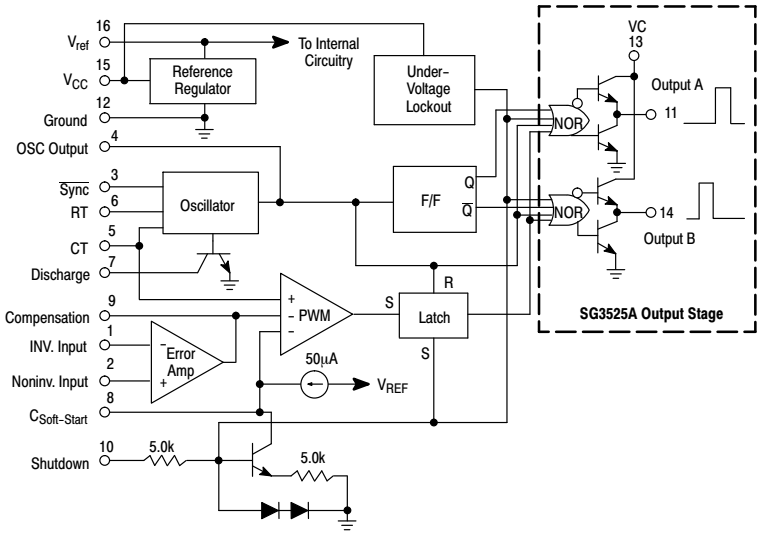


Figure 1. Representative Block Diagram

ORDERING INFORMATION

Device	Package	Shipping†
SG3525ANG	PDIP−16 (Pb−Free)	25 Units / Rail
SG3525ADWR2G	SOIC−16 WB (Pb−Free)	1000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage	V_{CC}	+40	Vdc
Collector Supply Voltage	V_C	+40	Vdc
Logic Inputs		−0.3 to +5.5	V
Analog Inputs		−0.3 to V_{CC}	V
Output Current, Source or Sink	I_O	±500	mA
Reference Output Current	I_{ref}	50	mA
Oscillator Charging Current		5.0	mA
Power Dissipation T_A = +25°C (Note 1) T_C = +25°C (Note 2)	P_D	 1000 2000	mW
Thermal Resistance, Junction−to−Air	$R_{\theta JA}$	100	°C/W
Thermal Resistance, Junction−to−Case	$R_{\theta JC}$	60	°C/W
Operating Junction Temperature	T_J	+150	°C
Storage Temperature Range	T_{stg}	−55 to +125	°C
Lead Temperature (Soldering, 10 seconds)	T_{Solder}	+300	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
1. Derate at 10 mW/°C for ambient temperatures above +50°C.
2. Derate at 16 mW/°C for case temperatures above +25°C.

RECOMMENDED OPERATING CONDITIONS

Characteristics	Symbol	Min	Max	Unit
Supply Voltage	V_{CC}	8.0	35	Vdc
Collector Supply Voltage	V_C	4.5	35	Vdc
Output Sink/Source Current (Steady State) (Peak)	I_O	 0 0	 ±100 ±400	mA
Reference Load Current	I_{ref}	0	20	mA
Oscillator Frequency Range	f_{osc}	0.1	400	kHz
Oscillator Timing Resistor	R_T	2.0	150	kΩ
Oscillator Timing Capacitor	C_T	0.001	0.2	μF
Deadtime Resistor Range	R_D	0	500	Ω
Operating Ambient Temperature Range	T_A	0	+70	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

APPLICATION INFORMATION

Shutdown Options (See Block Diagram, page 2)

Since both the compensation and soft−start terminals (Pins 9 and 8) have current source pull−ups, either can readily accept a pull−down signal which only has to sink a maximum of 100 μA to turn off the outputs. This is subject to the added requirement of discharging whatever external capacitance may be attached to these pins.

An alternate approach is the use of the shutdown circuitry of Pin 10 which has been improved to enhance the available shutdown options. Activating this circuit by applying a positive signal on Pin 10 performs two functions: the PWM latch is immediately set providing the fastest turn−off signal to the outputs; and a 150 μA current sink begins to discharge the external soft−start capacitor. If the shutdown command is short, the PWM signal is terminated without significant discharge of the soft−start capacitor, thus, allowing, for example, a convenient implementation of pulse−by−pulse current limiting. Holding Pin 10 high for a longer duration, however, will ultimately discharge this external capacitor, recycling slow turn−on upon release.

Pin 10 should not be left floating as noise pickup could conceivably interrupt normal operation.

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ELECTRICAL CHARACTERISTICS (V_{CC} = +20 Vdc, T_A = T_{low} to T_{high} [Note 3], unless otherwise noted.)

Characteristics	Symbol	Min	Typ	Max	Unit
REFERENCE SECTION					
Reference Output Voltage (T_J = +25°C)	V_{ref}	5.00	5.10	5.20	Vdc
Line Regulation (+8.0 V ≤ V_{CC} ≤ +35 V)	Reg_{line}	–	10	20	mV
Load Regulation (0 mA ≤ I_L ≤ 20 mA)	Reg_{load}	–	20	50	mV
Temperature Stability	$\Delta V_{ref}/\Delta T$	–	20	–	mV
Total Output Variation Includes Line and Load Regulation over Temperature	ΔV_{ref}	4.95	–	5.25	Vdc
Short Circuit Current (V_{ref} = 0 V, T_J = +25°C)	I_{SC}	–	80	100	mA
Output Noise Voltage (10 Hz ≤ f ≤ 10 kHz, T_J = +25°C)	V_n	–	40	200	μV_{rms}
Long Term Stability (T_J = +125°C) (Note 4)	S	–	20	50	mV/khr
OSCILLATOR SECTION (Note 5, unless otherwise noted.)					
Initial Accuracy (T_J = +25°C)		–	±2.0	±6.0	%
Frequency Stability with Voltage (+8.0 V ≤ V_{CC} ≤ +35 V)	$\frac{\Delta f_{osc}}{D V_{CC}}$	–	±1.0	±2.0	%
Frequency Stability with Temperature	$\frac{\Delta f_{osc}}{D T}$	–	±0.3	–	%
Minimum Frequency (R_T = 150 kΩ, C_T = 0.2 μF)	f_{min}	–	50	–	Hz
Maximum Frequency (R_T = 2.0 kΩ, C_T = 1.0 nF)	f_{max}	400	–	–	kHz
Current Mirror (I_{RT} = 2.0 mA)		1.7	2.0	2.2	mA
Clock Amplitude		3.0	3.5	–	V
Clock Width (T_J = +25°C)		0.3	0.5	1.0	μs
Sync Threshold		1.2	2.0	2.8	V
Sync Input Current (Sync Voltage = +3.5 V)		–	1.0	2.5	mA
ERROR AMPLIFIER SECTION (V_{CM} = +5.1 V)					
Input Offset Voltage	V_{IO}	–	2.0	10	mV
Input Bias Current	I_{IB}	–	1.0	10	μA
Input Offset Current	I_{IO}	–	–	1.0	μA
DC Open Loop Gain (R_L ≥ 10 MΩ)	A_{VOL}	60	75	–	dB
Low Level Output Voltage	V_{OL}	–	0.2	0.5	V
High Level Output Voltage	V_{OH}	3.8	5.6	–	V
Common Mode Rejection Ratio (+1.5 V ≤ V_{CM} ≤ +5.2 V)	CMRR	60	75	–	dB
Power Supply Rejection Ratio (+8.0 V ≤ V_{CC} ≤ +35 V)	PSRR	50	60	–	dB
PWM COMPARATOR SECTION					
Minimum Duty Cycle	DC_{min}	–	–	0	%
Maximum Duty Cycle	DC_{max}	45	49	–	%
Input Threshold, Zero Duty Cycle (Note 5)	V_{th}	0.6	0.9	–	V
Input Threshold, Maximum Duty Cycle (Note 5)	V_{th}	–	3.3	3.6	V
Input Bias Current	I_{IB}	–	0.05	1.0	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. T_{low} = 0° T_{high} = +70°C
4. Since long term stability cannot be measured on each device before shipment, this specification is an engineering estimate of average stability from lot to lot.
5. Tested at f_{osc} = 40 kHz (R_T = 3.6 kΩ, C_T = 0.01 μF, R_D = 0 Ω).

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ELECTRICAL CHARACTERISTICS (continued)

Characteristics	Symbol	Min	Typ	Max	Unit
SOFT−START SECTION					
Soft−Start Current ($V_{shutdown}$ = 0 V)		25	50	80	μA
Soft−Start Voltage ($V_{shutdown}$ = 2.0 V)		–	0.4	0.6	V
Shutdown Input Current ($V_{shutdown}$ = 2.5 V)		–	0.4	1.0	mA
OUTPUT DRIVERS (Each Output, V_{CC} = +20 V)					
Output Low Level (I_{sink} = 20 mA) (I_{sink} = 100 mA)	V_{OL}	 – –	 0.2 1.0	 0.4 2.0	V
Output High Level (I_{source} = 20 mA) (I_{source} = 100 mA)	V_{OH}	 18 17	 19 18	 – –	V
Under Voltage Lockout (V8 and V9 = High)	V_{UL}	6.0	7.0	8.0	V
Collector Leakage, V_C = +35 V (Note 6)	$I_{C(leak)}$	–	–	200	μA
Rise Time (C_L = 1.0 nF, T_J = 25°C)	t_r	–	100	600	ns
Fall Time (C_L = 1.0 nF, T_J = 25°C)	t_f	–	50	300	ns
Shutdown Delay (V_{DS} = +3.0 V, C_S = 0, T_J = +25°C)	t_{ds}	–	0.2	0.5	μs
Supply Current (V_{CC} = +35 V)	I_{CC}	–	14	20	mA

6. Applies to SG3525A only, due to polarity of output pulses.

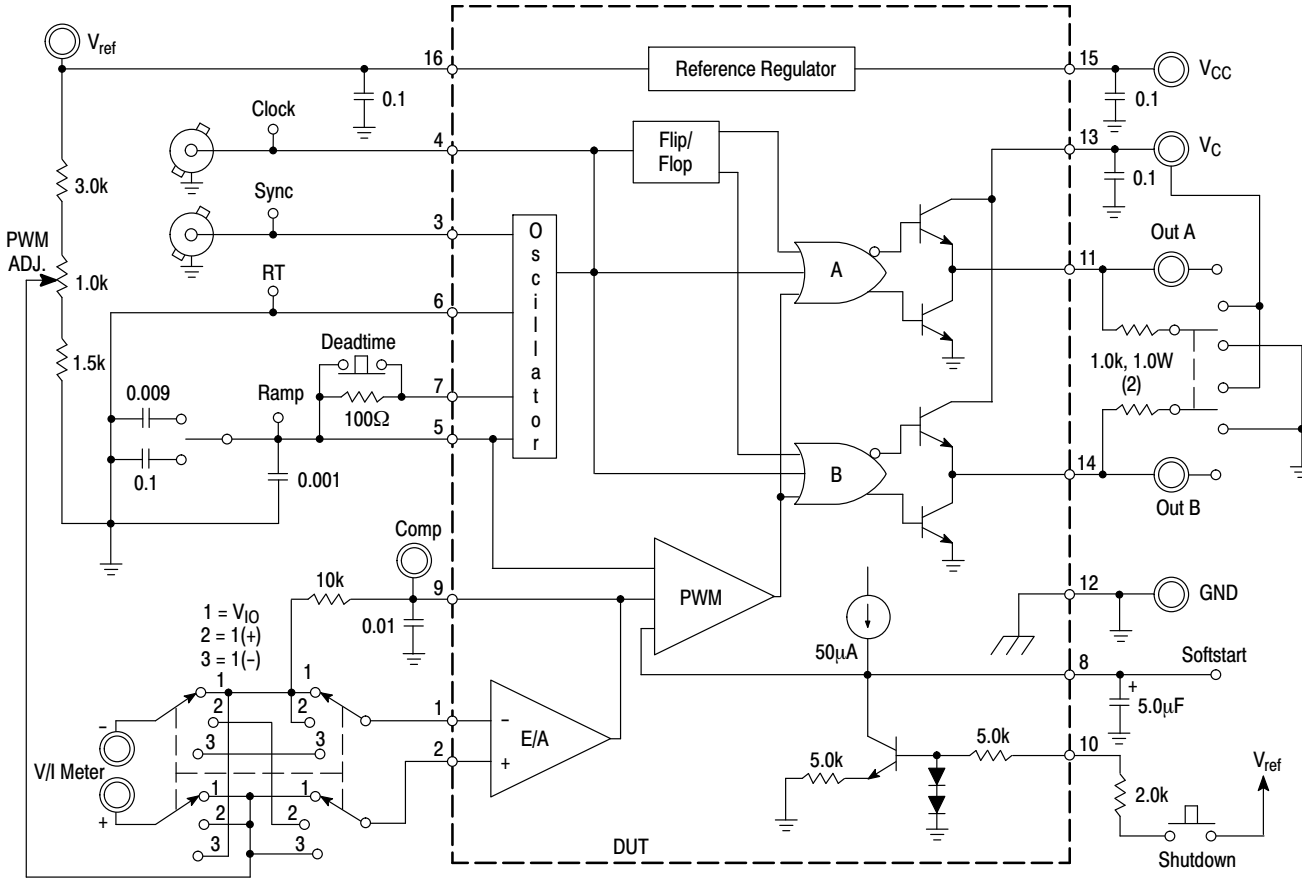


Figure 2. Lab Test Fixture

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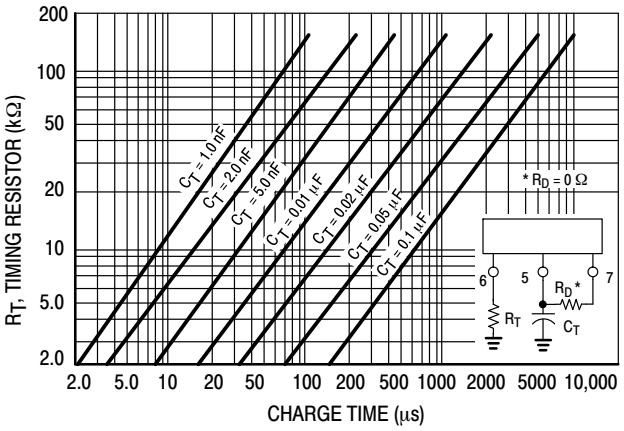


Figure 3. Oscillator Charge Time versus R_T

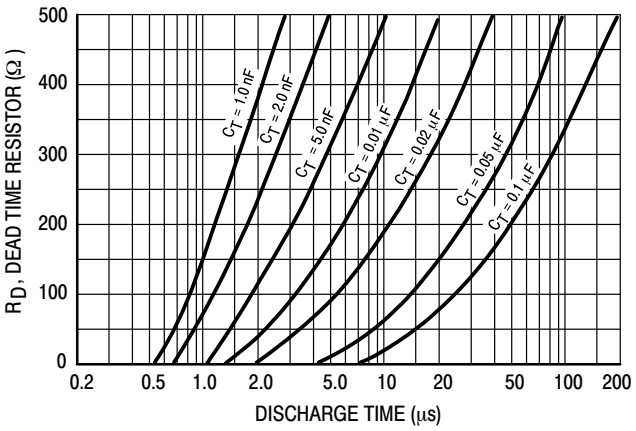


Figure 4. Oscillator Discharge Time versus R_D

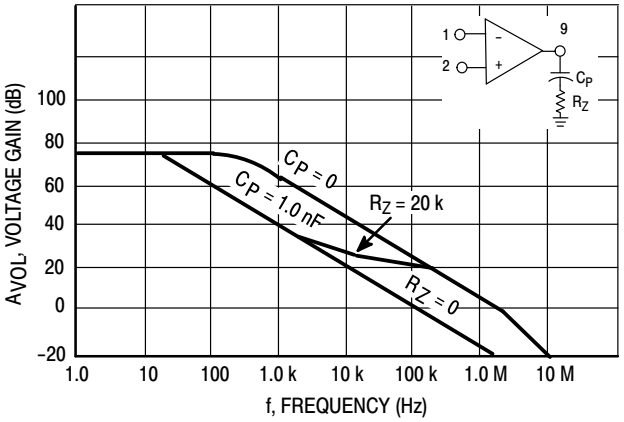


Figure 5. Error Amplifier Open Loop Frequency Response

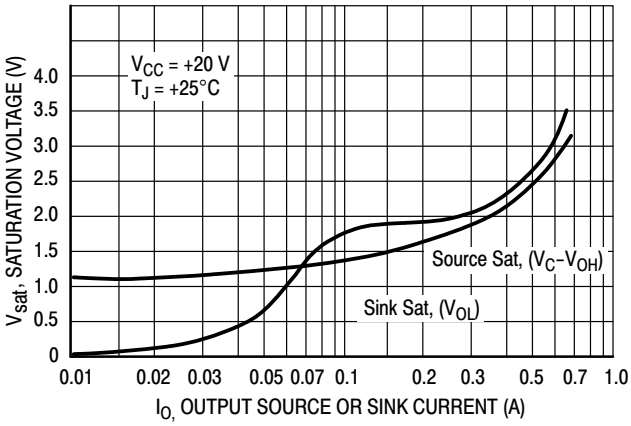


Figure 6. Output Saturation Characteristics

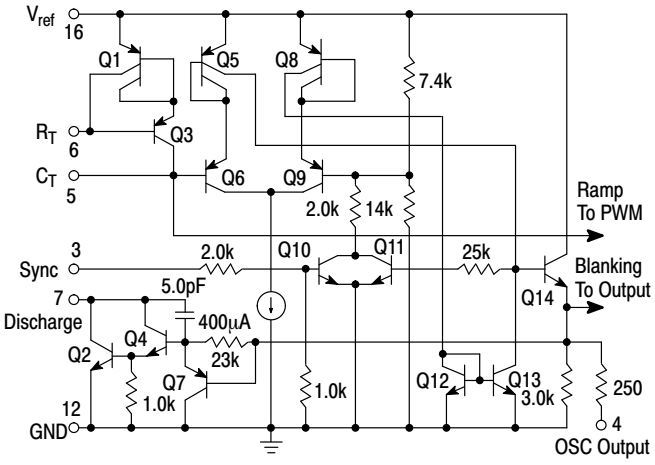


Figure 7. Oscillator Schematic

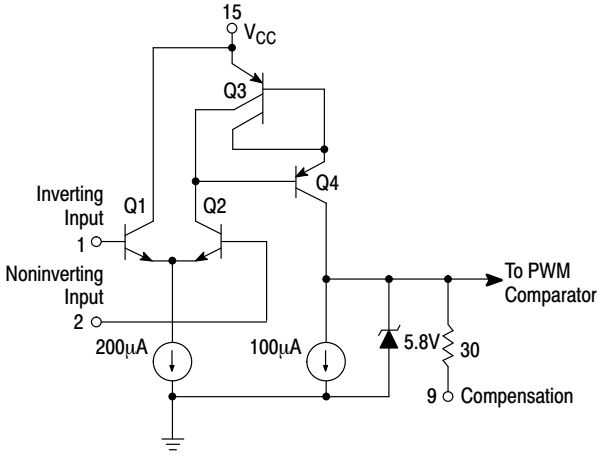


Figure 8. Error Amplifier Schematic

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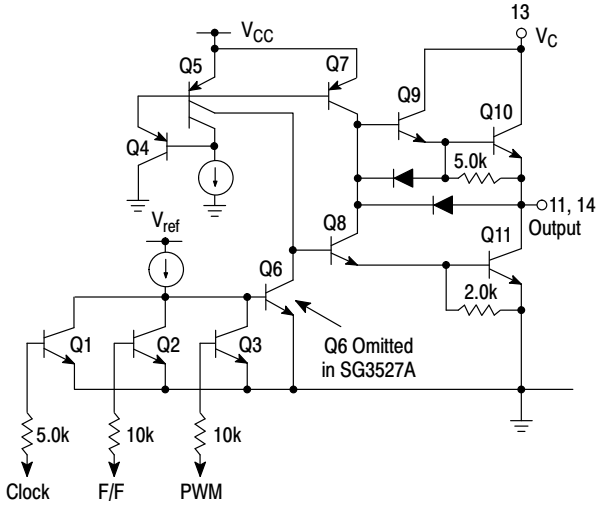
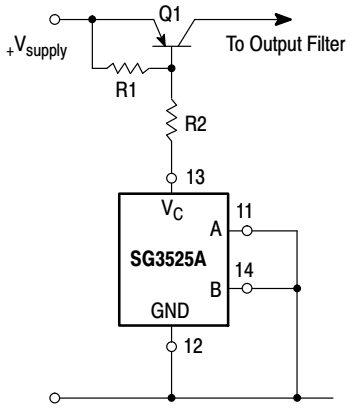
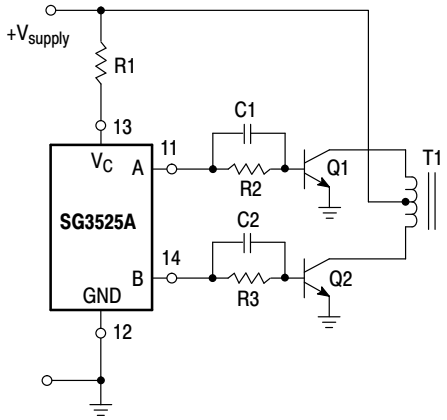


Figure 9. Output Circuit
(1/2 Circuit Shown)



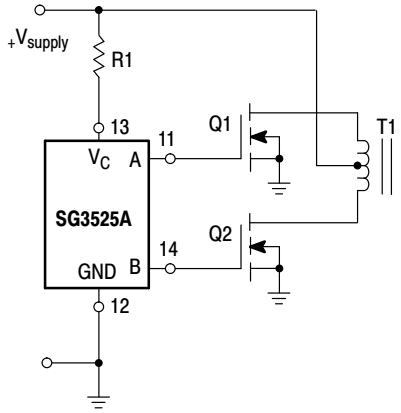
For single−ended supplies, the driver outputs are grounded. The V_C terminal is switched to ground by the totem−pole source transistors on alternate oscillator cycles.

Figure 10. Single−Ended Supply



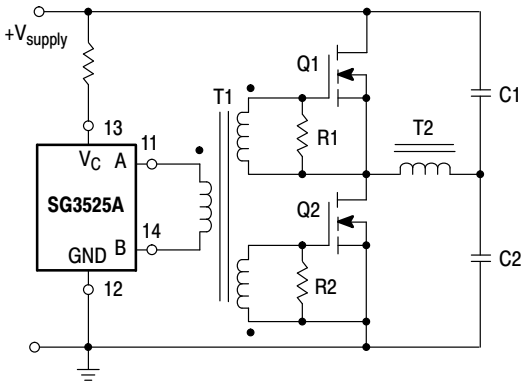
In conventional push−pull bipolar designs, forward base drive is controlled by R1−R3. Rapid turn−off times for the power devices are achieved with speed−up capacitors C1 and C2.

Figure 11. Push−Pull Configuration



The low source impedance of the output drivers provides rapid charging of power FET input capacitance while minimizing external components.

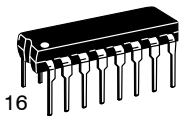
Figure 12. Driving Power FETS



Low power transformers can be driven directly by the SG3525A. Automatic reset occurs during deadtime, when both ends of the primary winding are switched to ground.

Figure 13. Driving Transformers in a Half−Bridge Configuration

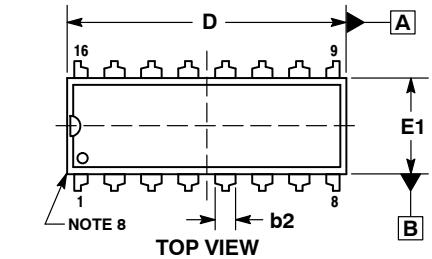
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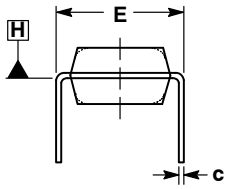
SCALE 1:1

PDIP−16
CASE 648−08
ISSUE V

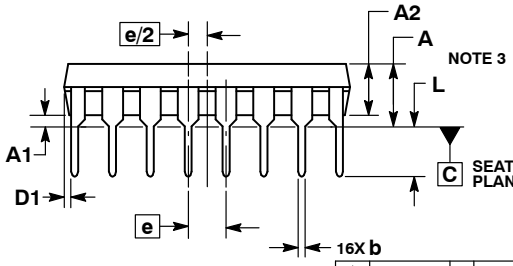
DATE 22 APR 2015



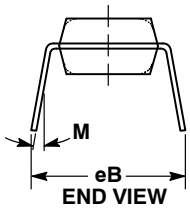
TOP VIEW



END VIEW
WITH LEADS CONSTRAINED
NOTE 5



SIDE VIEW



END VIEW
NOTE 6

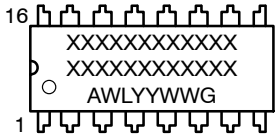
NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACKAGE SEATED IN JEDEC SEATING PLANE GAUGE GS−3.
4. DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE NOT TO EXCEED 0.10 INCH.
5. DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR TO DATUM C.
6. DIMENSION eB IS MEASURED AT THE LEAD TIPS WITH THE LEADS UNCONSTRAINED.
7. DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY.
8. PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE CORNERS).

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	----	0.210	---	5.33
A1	0.015	----	0.38	---
A2	0.115	0.195	2.92	4.95
b	0.014	0.022	0.35	0.56
b2	0.060 TYP		1.52 TYP	
C	0.008	0.014	0.20	0.36
D	0.735	0.775	18.67	19.69
D1	0.005	----	0.13	---
E	0.300	0.325	7.62	8.26
E1	0.240	0.280	6.10	7.11
e	0.100 BSC		2.54 BSC	
eB	----	0.430	---	10.92
L	0.115	0.150	2.92	3.81
M	----	10°	---	10°

STYLE 1:
PIN 1. CATHODE
2. CATHODE
3. CATHODE
4. CATHODE
5. CATHODE
6. CATHODE
7. CATHODE
8. CATHODE
9. ANODE
10. ANODE
11. ANODE
12. ANODE
13. ANODE
14. ANODE
15. ANODE
16. ANODE

STYLE 2:
PIN 1. COMMON DRAIN
2. COMMON DRAIN
3. COMMON DRAIN
4. COMMON DRAIN
5. COMMON DRAIN
6. COMMON DRAIN
7. COMMON DRAIN
8. COMMON DRAIN
9. GATE
10. SOURCE
11. GATE
12. SOURCE
13. GATE
14. SOURCE
15. GATE
16. SOURCE

GENERIC MARKING DIAGRAM*



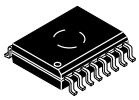
XXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

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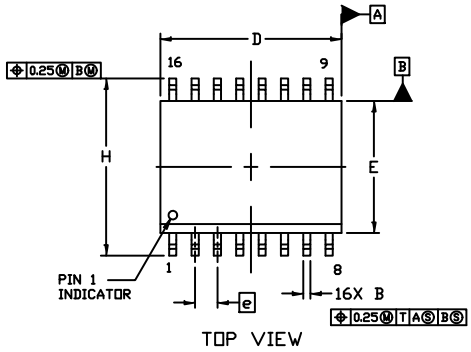


1

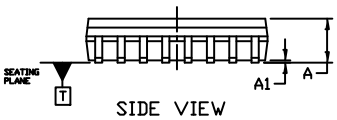
SCALE 1:1

SOIC−16 WB
CASE 751G
ISSUE E

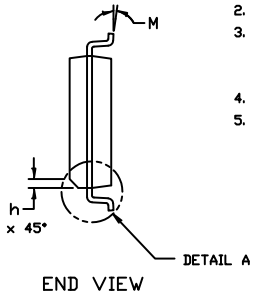
DATE 08 OCT 2021



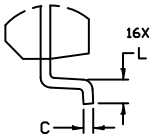
TOP VIEW



SIDE VIEW



END VIEW

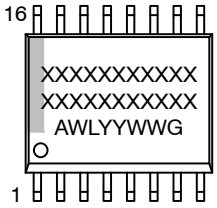


DETAIL A
2X SCALE

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION OR FLASH TO BE 0.15 PER SIDE.

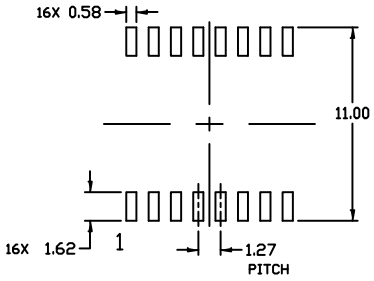
	MILLIMETERS	
DIM	MIN.	MAX.
A	2.35	2.65
A1	0.10	0.25
B	0.35	0.49
C	0.23	0.32
D	10.15	10.45
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.53 REF	
L	0.50	0.90
M	0°	7°

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.



RECOMMENDED
MOUNTING FOOTPRINT

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DESCRIPTION:	**SOIC−16 WB**		**PAGE 1 OF 1**

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